TENTATIVE

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

HN9C08FT

VHF~UHF BAND LOW NOISE AMPLIFIER APPLICATIONS

• TWO devices are built in to the super-thin and ultra super mini (6pins) package: TU6

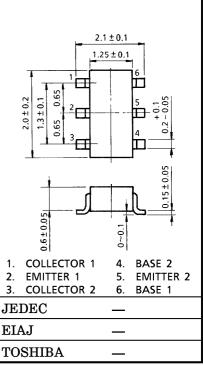
MOUNTED DEVICES

	Q1	Q2
Three-pins (SSM) mold products are corresponded.	2SC5091	2SC5091

MAXIMUM RATINGS (Ta = 25°C)

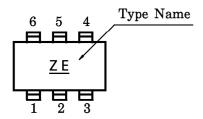
CHARACTERISTIC	SYMBOL	Q1/Q2	UNIT
Collector-Base Voltage	v_{CBO}	20	V
Collector-Emitter Voltage	v_{CEO}	8	V
Emitter-Base Voltage	$V_{ m EBO}$	1.5	V
Collector Current	IC	40	mA
Base Current	$I_{ m B}$	20	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	200	mW
Junction Temperature	T_{j}	125	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	°C

Unit in mm

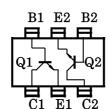


Weight: 0.008g

MARKING



PIN ASSIGNMENT (TOP VIEW)



1 2001-05-31

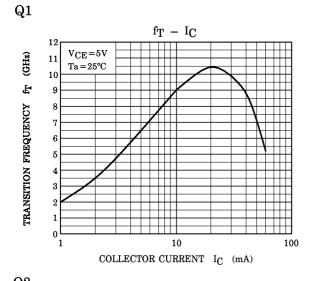
ELECTRICAL CHARACTERISTICS Q1 (Ta = 25°C)

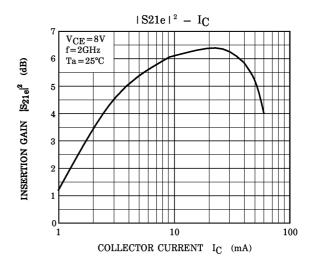
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	$V_{CB} = 10V, I_{E} = 0$	_	_	1	μ A
Emitter Cut-off Current	I _{EBO}	$V_{EB} = 1V, I_C = 0$	_		1	μ A
DC Current Gain	$h_{ ext{FE}}$	$V_{CE}=8V, I_{C}=20mA$	50	_	160	_
Transition Frequency	${ m f_T}$	$V_{CE}=8V, I_{C}=20mA$	7	10	_	GHz
Insertion Gain	$ S_{21e} ^2(1)$	V _{CE} =8V, I _C =20mA, f=1000MHz	_	14	_	dB
	$ S_{21e} ^2$ (2)	V _{CE} =8V, I _C =20mA, f=2000MHz	4	6.5	_	dB
Noise Figure	NF (1)	$V_{CE} = 8V, I_{C} = 5mA, f = 1000MHz$	_	1.1	_	dB
	NF (2)	$V_{CE} = 8V, I_{C} = 5mA, f = 2000MHz$	_	1.7	3	dB

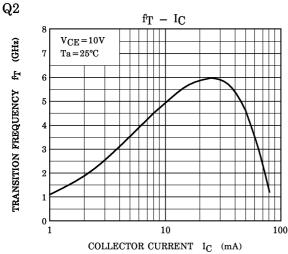
ELECTRICAL CHARACTERISTICS Q2 (Ta = 25°C)

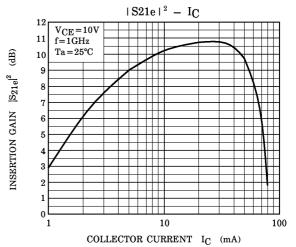
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	$V_{CB} = 10V, I_{E} = 0$	_	_	1	μ A
Emitter Cut-off Current	I_{EBO}	$V_{EB}=1V, I_{C}=0$	_	_	1	μ A
DC Current Gain	$h_{ extbf{FE}}$	$V_{CE}=6V, I_{C}=7mA$	50	_	160	_
Transition Frequency	${ m f_T}$	$V_{CE}=6V, I_{C}=7mA$	7	10	_	GHz
Insertion Gain	$ S_{21e} ^2$ (1)	$V_{CE} = 6V, I_{C} = 7mA, f = 1000MHz$		14	_	dB
	$ S_{21e} ^2$ (2)	$V_{CE} = 6V, I_{C} = 7mA, f = 2000MHz$	4.5	7	_	dB
Noise Figure	NF (1)	$V_{CE} = 6V, I_{C} = 3mA, f = 1000MHz$	_	1.1	_	dB
	NF (2)	$V_{CE} = 6V, I_{C} = 3mA, f = 2000MHz$		1.7	3	dB

2 2001-05-31









3 2001-05-31

RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- ◆ The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.